

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1301	(313/503).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 17:13
L2	3606	(313/504).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 17:13
L3	3596	(313/506).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 17:13
L4	5620	L1 L2 L3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 17:14
L5	4907	L4 and (ITO IZO IXO ((indium tin Sn zinc Zn gallium Ga vanadium V antimony Sb bismuth Bi rhenium Re tantalum Ta tungsten W niobium Nb nickel Ni) with oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 17:16
L7	1358	L4 and ((ITO IZO IXO ((indium tin Sn zinc Zn gallium Ga vanadium V antimony Sb bismuth Bi rhenium Re tantalum Ta tungsten W niobium Nb nickel Ni) with oxide)) same (resistance resistivit\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 17:17
L8	957	L4 and ((ITO IZO IXO ((indium tin Sn zinc Zn gallium Ga vanadium V antimony Sb bismuth Bi rhenium Re tantalum Ta tungsten W niobium Nb nickel Ni) with oxide)) with (resistance resistivit\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 17:32
L9	1112	L4 and ((ITO IZO IXO ((indium tin Sn zinc Zn gallium Ga vanadium V antimony Sb bismuth Bi rhenium Re tantalum Ta tungsten W niobium Nb nickel Ni) with oxide)) with (fluoride nitride sulfide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/18 17:18

## EAST Search History

L10	112	L4 and (((ITO IZO IXO ((indium tin Sn zinc Zn gallium Ga vanadium V antimony Sb bismuth Bi rhenium Re tantalum Ta tungsten W niobium Nb nickel Ni) with oxide)) with (fluoride nitride sulfide)) same (resistance resistivit\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/18 17:32
L11	114	L4 and (((ITO IZO IXO ((indium tin Sn zinc Zn gallium Ga vanadium V antimony Sb bismuth Bi rhenium Re tantalum Ta tungsten W niobium Nb nickel Ni) with oxide)) with (fluoride nitride sulfide)) same (resistance resistivit\$4 ohm\$2))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/18 17:39
L12	996	L4 and ((ITO IZO IXO ((indium tin Sn zinc Zn gallium Ga vanadium V antimony Sb bismuth Bi rhenium Re tantalum Ta tungsten W niobium Nb nickel Ni) with oxide)) with (resistance resistivit\$4 ohm\$2))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/18 18:05
L13	129	L4 and ((short\$4 leak\$4) same (resistance resistivit\$4 ohm\$2) same thick\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/18 17:51
L14	13	L11 and L13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/18 17:49